

TOSHIBA TRANSISTOR SILICON NPN EPITAXIAL TYPE (PCT PROCESS)

2SC2500

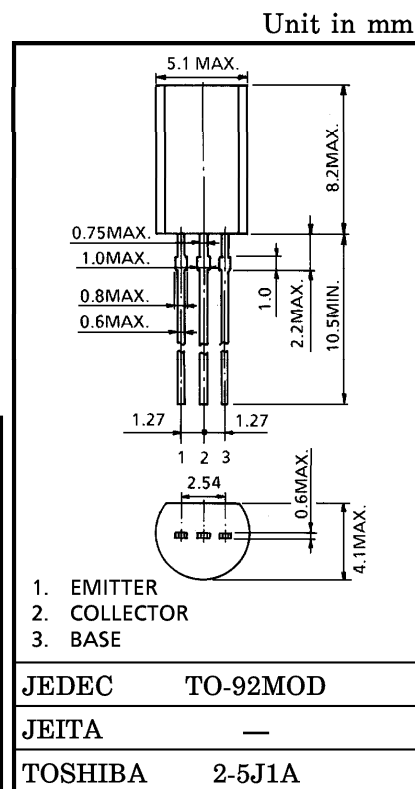
STROBE FLASH APPLICATIONS

MEDIUM POWER AMPLIFIER APPLICATIONS

- High DC Current Gain and Excellent h_{FE} Linearity
 : $h_{FE}(1) = 140 \sim 600$ ($V_{CE} = 1V$, $I_C = 0.5A$)
 : $h_{FE}(2) = 70$ (Min.), 200 (Typ.) ($V_{CE} = 1V$, $I_C = 2A$)
- Low Saturation Voltage
 : $V_{CE(sat)} = 0.5V$ (Max.) ($I_C = 2A$, $I_B = 50mA$)

MAXIMUM RATINGS ($T_a = 25^\circ C$)

CHARACTERISTIC		SYMBOL	RATING	UNIT
Collector-Base Voltage		V_{CBO}	30	V
Collector-Emitter Voltage		V_{CES}	30	V
		V_{CEO}	10	
Emitter-Base Voltage		V_{EBO}	6	V
Collector Current	DC	I_C	2	A
	Pulsed (Note 1)	I_{CP}	5	
Base Current		I_B	0.5	A
Collector Power Dissipation		P_C	900	mW
Junction Temperature		T_j	150	$^\circ C$
Storage Temperature Range		T_{stg}	$-55 \sim 150$	$^\circ C$



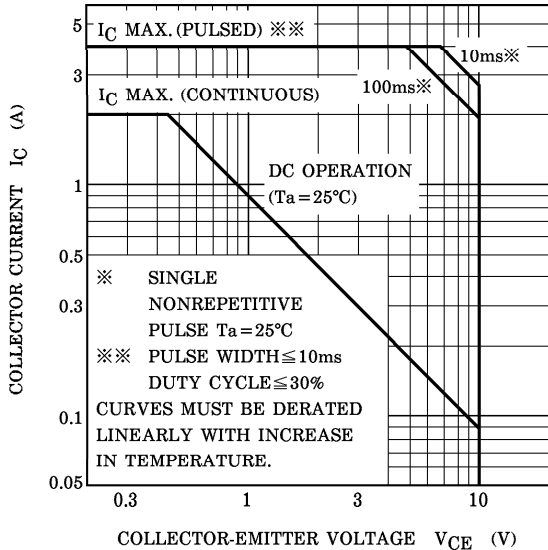
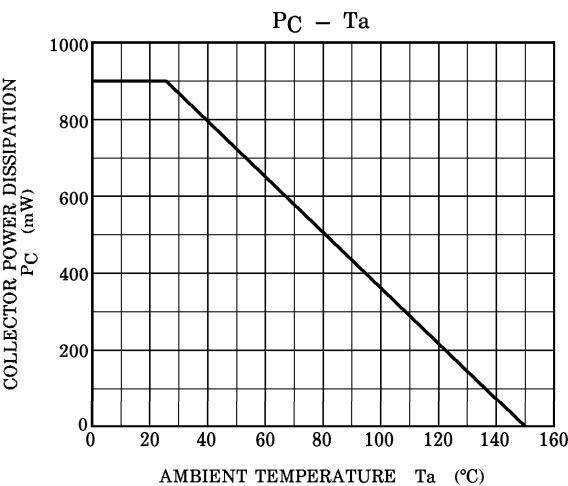
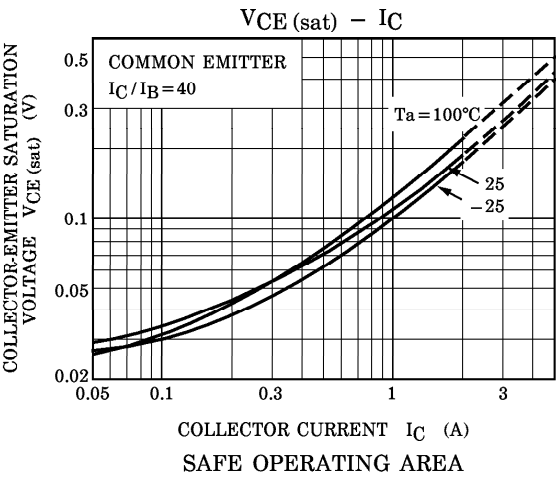
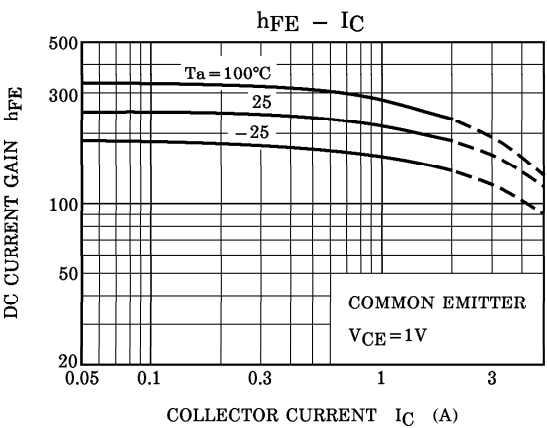
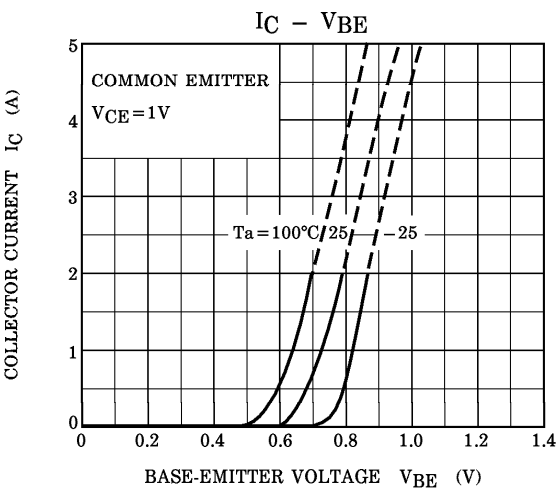
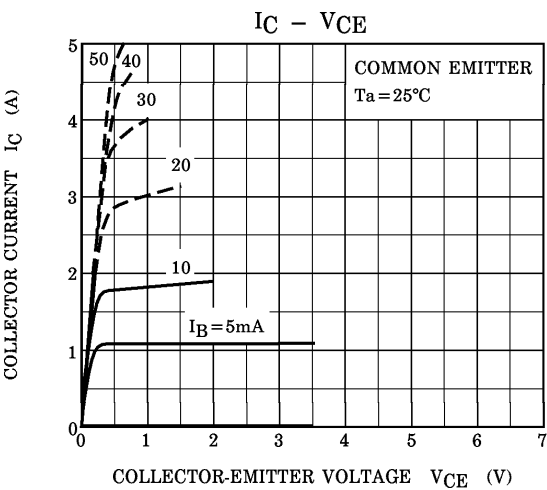
Weight : 0.36g (Typ.)

(Note 1) : Pulse Width $\leq 10ms$, Duty Cycle $\leq 30\%$ ELECTRICAL CHARACTERISTICS ($T_a = 25^\circ C$)

CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Collector Cut-off Current	I_{CBO}	$V_{CB} = 30V$, $I_E = 0$	—	—	100	nA
Emitter Cut-off Current	I_{EBO}	$V_{EB} = 6V$, $I_C = 0$	—	—	100	nA
Collector-Emitter Breakdown Voltage	V_{CEO}	$I_C = 10mA$, $I_B = 0$	10	—	—	V
Emitter-Base Breakdown Voltage	V_{EBO}	$I_E = 1mA$, $I_C = 0$	6	—	—	V
DC Current Gain	$h_{FE}(1)$ (Note 2)	$V_{CE} = 1V$, $I_C = 0.5A$	140	—	600	
	$h_{FE}(2)$	$V_{CE} = 1V$, $I_C = 2A$	70	200	—	
Collector-Emitter Saturation Voltage	$V_{CE(sat)}$	$I_C = 2A$, $I_B = 50mA$	—	0.2	0.5	V
Base-Emitter Voltage	V_{BE}	$V_{CE} = 1V$, $I_C = 2A$	—	0.86	1.5	V
Transition Frequency	f_T	$V_{CE} = 1V$, $I_C = 0.5A$	—	150	—	MHz
Collector Output Capacitance	C_{ob}	$V_{CB} = 10V$, $I_E = 0$, $f = 1MHz$	—	27	—	pF

(Note 2) : $h_{FE}(1)$ Classification

A : 140~240, B : 200~330, C : 300~450, D : 420~600



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